

MBRF2535CT - MBRF25150CT



Isolated 25.0 AMPS. Schottky Barrier Rectifiers **ITO-220AB**

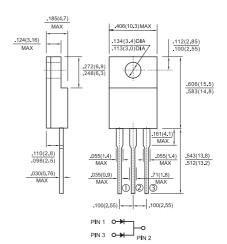


Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
 For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- Cases: ITO-220AB molded plastic body
- Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- \diamond Mounting position: Any
- Mounting torque: 5 in-lbs. Max.
- Weight: 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

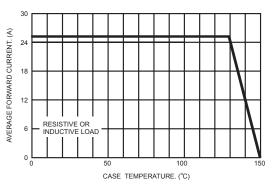
Type Number	Symbol	2535 CT	2545 CT	2550 CT	2560 CT	2590 CT	25100 CT	СТ	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	V
Maximum Working Peak Reverse Voltage	V_{RMS}	24	31	35	42	63	70	105	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	V
Maximum Average Forward Rectified Current at T _c =130°C Total device Per Leg	I _(AV)	25 12.5							Α
Peak Repetitive Forward Current Per leg (Rated V _R , Square Wave, 20KHz) at Tc=130°C	I_{FRM}	25							Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	200							Α
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0			0.5			Α	
Maximum Instantaneous Forward Voltage at (Note 2) $I_F=12.5A$, $T_C=25^{\circ}C$ $I_F=12.5A$, $T_C=125^{\circ}C$ $I_F=25A$, $T_C=25^{\circ}C$ $I_F=25A$, $T_C=125^{\circ}C$	V_{F}	_ _ 0.82 0.73			0.75 0.65 - 0.9 - 0.8		75 92	0.95 0.92 1.02 0.98	٧
Maximum Instantaneous Reverse Current @ Tc=25 °C at Rated DC Blocking Voltage Per Leg @ Tc=125 °C	I _R		.2 5		.2 0	0 7	.1 .5	0.1 5	mA mA
Voltage Rate of Change, (Rated V _R)	dV/dt	1,000						V/uS	
Typical Junction Capacitance	Cj	580			480			pF	
RMS Isolation Voltage (MBRF Type only) from Terminals to Heatsink with t=1.0 second, RH≤30%	V_{ISO}	4500 (Note 4) 3500 (Note 5) 1500 (Note 6)							٧
Maximum Thermal Resistance Per Leg (Note 3)	$R_{\scriptscriptstyle{ hetaJA}}$ $R_{\scriptscriptstyle{ hetaJC}}$	8.0 1.0							°C/W
Operating Junction Temperature Range	TJ	-65 to +150						°C	
Storage Temperature Range	Tstg	-65 to +175							°C

- Notes
- 2.0us Pulse Width, f=1.0 KHz
- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. Thermal Resistance from Junction to Case Per Leg, with Heatsink size (4"x6"x0.25") Al-Plate.
 4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.
- 5. Clip Mounting (on case), where leads do overlap heatsink.
- 6. Screw Mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19").



RATINGS AND CHARACTERISTIC CURVES (MBRF2535CT THRU MBRF25150CT)





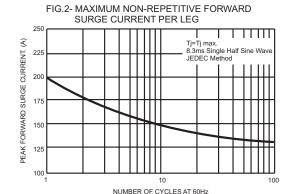
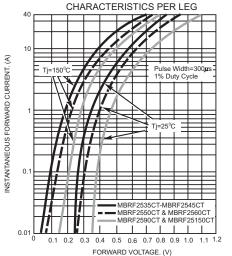


FIG.3- TYPICAL INSTANTANEOUS FORWARD





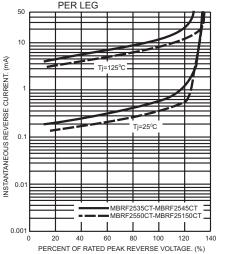


FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG

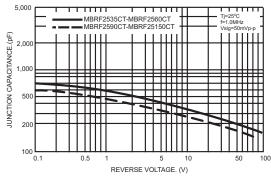


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG

